

Typical $f_t \cong 180$ mc (See Outline Drawing No. 16)

Type	MINIMUM		MAXIMUM						Comments						
	h_{FE} Min. Max. @ I_C	$V_{CE}=10v$ $I_C=4$ ma $f=100$ mc	h_{re}	V_{CEO} Volts @ I_C	V_{EB0} Volts @ I_E	$V_{BE} (SAT)$ $I_C=10$ ma $I_B=1$ ma	$V_{CE} (SAT)$ $I_C=10$ ma $I_B=1$ ma	I_{CBO} $T_J=150^\circ C$ @ V_{CB}	V_{BE} (SAT)	V_{CE} (SAT)	$C_{ob} @ V_{CB}$	pF	Volts		
2N929	.01 5.0 40-120	—	10	45	100	5	0.6-1 ⁽²⁾	1.0 ⁽²⁾	45	10	—	—	5(TYP)		
2N930	.01 5.0 100-300	—	10	45	100	5	0.6-1 ⁽²⁾	1.0 ⁽²⁾	45	10	—	—	5(TYP)		
2N2483	.01 5.0 40-120	—	10	60	10	6	—	.35 ⁽³⁾	45	10	—	—	5(TYP)		
2N2484	.01 5.0 100-500	—	10	60	10	6	—	.35 ⁽³⁾	45	10	—	—	5(TYP)		

Typical $f_t \cong 300$ mc (See Outline Drawing No. 16)

Type	MINIMUM		MAXIMUM						Comments						
	h_{FE} Min. Max. @ I_C	$V_{CE}=10v$ $I_C=4$ ma $f=100$ mc	h_{re}	V_{CEO} Volts @ I_C	V_{EB0} Volts @ I_E	$V_{BE} (SAT)$ $I_C=10$ ma $I_B=1$ ma	$V_{CE} (SAT)$ $I_C=10$ ma $I_B=1$ ma	I_{CBO} $T_J=150^\circ C$ @ V_{CB}	V_{BE} (SAT)	V_{CE} (SAT)	$C_{ob} @ V_{CB}$	pF	Volts		
2N759	1.0 5.0 36-90	—	1.0	45	100	8	—	1.0	30	200	—	—	8	5	These devices are well suited for applications where the 2N335 and 2N336 have been used and higher frequency devices or smaller packages are required.
2N760	1.0 5.0 76-333	—	1.0	45	100	8	—	1.0	30	200	—	—	8	5	
2N915	10 5.0 40-160	—	10	50	100	5	0.9	1.0	60	30	—	—	3.5	10	These devices are intended for non-saturating switching circuits, amplifier and oscillator circuits.
2N916	10 1.0 50-200	—	30	25	10	5	0.9	0.5	15	10	—	—	6	5	